



March 2009

FAN7080_F085 Half Bridge Gate Driver

FAN7080_F085 Half Bridge Gate Driver

Features

- Qualified to AEC Q100
- Floating channel designed for bootstrap operation fully operational to + 600V
- Tolerance to negative transient voltage on VS pin
- VS-pin dv/dt immune.
- Gate drive supply range from 5.5V to 20V
- Under-voltage lockout
- CMOS Schmitt-triggered inputs with pull-down
- High side output in phase with input
- IN input is 3.3V/5V logic compatible and available on 15V input
- Matched propagation delay for both channels
- Dead time adjustable

Typical Applications

- Junction Box
- Half and full bridge application in the motor drive system

Description

The FAN7080_F085_F085 is a half-bridge gate drive IC with reset input and adjustable dead time control. It is designed for high voltage and high speed driving of MOSFET or IGBT, which operates up to 600V. Fairchild's high-voltage process and common-mode noise cancellation technique provide stable operation in the high side driver under high-dV/dt noise circumstances. An advanced level-shift circuit allows high-side gate driver operation up to VS=-5V (typical) at VBS=15V. Logic input is compatible with standard CMOS outputs. The UVLO circuits for both channels prevent from malfunction when VCC and VBS are lower than the specified threshold voltage. Combined pin function for dead time adjustment and reset shutdown make this IC packaged with space saving SOIC-8 Package. Minimum source and sink current capability of output driver is 250mA and 500mA respectively, which is suitable for junction box application and half and full bridge application in the motor drive system.

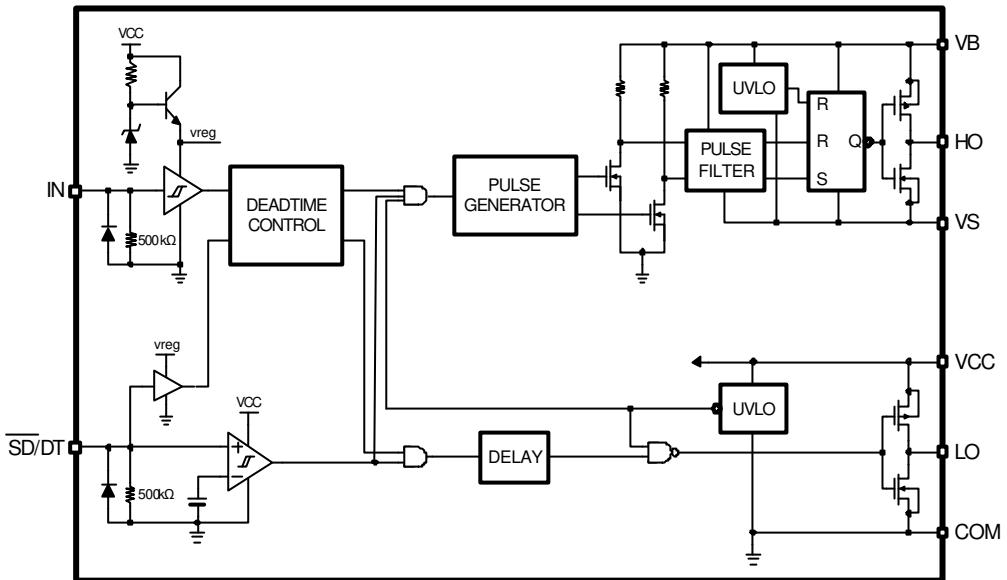


Ordering Information

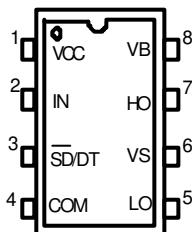
| Device | Package | Operating Temp. |
|------------|---------|-----------------|
| FAN7080CM | SOIC-8 | -40 °C ~ 125 °C |
| FAN7080CMX | SOIC-8 | -40 °C ~ 125 °C |

X : Tape & Reel type

Block Diagrams



Pin Assignments



Pin Definitions

| Pin Number | Pin Name | I/O | Pin Function Description |
|------------|----------|-----|--|
| 1 | VCC | P | Driver supply voltage |
| 2 | IN | I | Logic input for high and low side gate drive output |
| 3 | SD/DT | I | Shut down input and dead time setting |
| 4 | COM | P | Ground |
| 5 | LO | A | Low side gate drive output for MOSFET Gate connection |
| 6 | VS | A | High side floating offset for MOSFET Source connection |
| 7 | HO | A | High side drive output for MOSFET Gate connection |
| 8 | VB | P | Driver output stage supply |

Absolute Maximum Ratings

Absolute Maximum Ratings indicate sustained limits beyond which damage to the device may occur. All voltage parameters are absolute voltages referenced to COM.

| Parameter | Symbol | Min. | Max. | Unit |
|--|-------------------|---------------------|-----------------------|------|
| High side floating supply offset voltage | V _s | V _B -25 | V _B +0.3 | V |
| High side floating supply voltage | V _B | -0.3 | 625 | V |
| High side floating output voltage | V _{HO} | V _s -0.3 | V _B +0.3 | V |
| Low side output voltage | V _{LO} | -0.3 | V _{CC} + 0.3 | V |
| Supply voltage | V _{CC} | -0.3 | 25 | V |
| Input voltage for I _N | V _{IN} | -0.3 | V _{CC} +0.3 | V |
| Input injection current. Full function, no latch up;(Guaranteed by design). Test at 10V and 17V on Eng.Samples | I _N | - | +1 | mA |
| Power Dissipation | P _d | | 0.625 | W |
| Thermal resistance, junction to ambient | R _{thja} | | 200 | °C/W |
| Electrostatic discharge voltage (Human Body Model) | V _{ESD} | 1 K | | V |
| Charge device model | V _{CDM} | 500 | | V |
| Junction Temperature | T _j | | 150 | °C |
| Storage Temperature | T _S | -55 | 150 | °C |

Note: 1) The thermal resistance and power dissipation rating are measured bellow conditions;

JESD51-2: Integrated Circuit Thermal Test Method Environmental Conditions - Natural convection(StillAir)

JESD51-3 : Low Effective Thermal Conductivity Test Board for Leaded Surface Mount Package

Recommended Operating Conditions

For proper operation the device should be used within the recommended conditions.

| Parameter | Symbol | Min. | Max. | Unit |
|--|------------------------------|--------------------|---------------------|------|
| High side floating supply voltage(DC) Transient:-10V@ 0.1 us | V _B ¹⁾ | V _s + 6 | V _s + 20 | V |
| High side floating supply offset voltage(DC) Transient: -25V(max) @0.1us @VBS<25V | V _s | -5 | 600 | V |
| High side floating output voltage | V _{HO} | V _s | V _B | V |
| Low side output voltage | V _{LO} | 0 | V _{CC} | V |
| Allowable offset voltage Slew Rate ²⁾ | dV/dt | - | 50 | V/ns |
| Supply voltage for logic part | V _{CC} | 5.5 | 20 | V |
| Logic input voltage | V _{IN} | 0 | V _{CC} | V |
| Switching Frequency ³⁾ | F _s | | 200 | KHz |
| Ambient Temperature | T _a | -40 | 125 | °C |

Note: 1) The V_s offset is tested with all supplies biased at 15V differential.

2) Guaranteed by design.

3) When VDT= 1.2V.

Statics Electrical Characteristics

Unless otherwise specified, -40°C <= Ta <= 125°C, Vcc = 15V, Vbs = 15V, Vs = 0V, CL = 1nF.

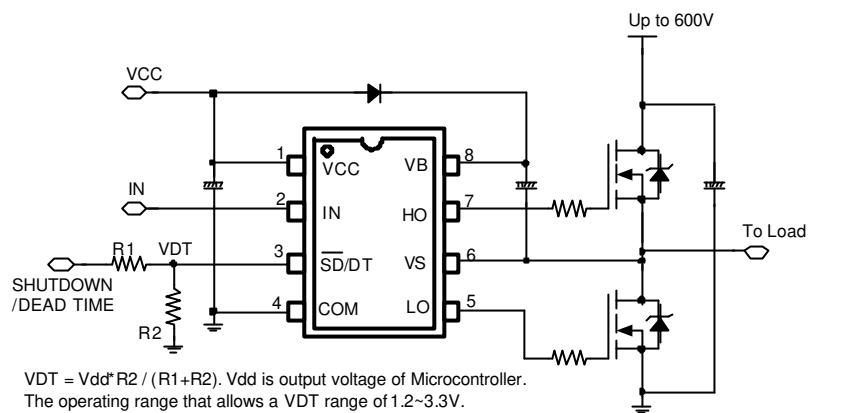
| Parameter | Symbol | Conditions | Min. | Typ. | Max. | Unit |
|---|------------------|--|------------|--------|----------|----------|
| Vcc and VBS supply Characteristics | | | | | | |
| Vcc and Vbs supply under voltage positive going threshold | VCCUV+ VBSUV+ | - | - | 4.2 | 5.5 | V |
| Vcc and Vbs supply under voltage negative going threshold | VCCUV- VBSUV- | - | 2.8 | 3.6 | - | V |
| Vcc and Vbs supply under voltage hysteresis | VCCUVH VBSUVH | - | 0.2 | 0.6 | - | V |
| Under voltage lockout response time | tduvcc tduvbs | VCC: 6V-->2.5V or 2.5V-->6V VBS: 6V-->2.5V or 2.5V-->6V | 0.5 0.5 | - - | 20 20 | us us |
| Offset supply leakage current | ILK | VB=Vs=600V | - | 20 | 50 | uA |
| Quiescent Vbs supply current | IQBS | VIN=0 OR 5V, VS DT = 1.2V | 20 | 75 | 150 | uA |
| Quiescent Vcc supply current | IQCC | VIN=0 OR 5, VS DT = 1.2V | - | 350 | 1000 | uA |
| Input Characteristics | | | | | | |
| High logic level input voltage | VIH | | 2.7 | - | - | V |
| Low logic level input voltage | VIL | | - | - | 0.8 | V |
| High logic level input bias current for IN | IIN+ | VIN=5V | - | 10 | 50 | uA |
| Low logic level input bias current for IN | IIN- | VIN=0V | - | 0 | 2 | uA |
| VS DT dead time setting range | VDT | | 1.2 | - | 5 | V |
| VS DT shutdown threshold voltage | VSD | | - | 0.8 | 1.2 | V |
| High logic level resistance for SD/DT | RSDT | VS DT=5V | 100 | 500 | 1100 | KΩ |
| Low logic level input bias current for SD/DT | ISDT- | VS DT=0V | - | 1 | 2 | uA |
| Output characteristics | | | | | | |
| High level output voltage, Vcc-VHO | VOH(HO) | Io=0 | - | - | 0.1 | V |
| Low level output voltage, VHO | VOL(HO) | Io=0 | - | - | 0.1 | V |
| Output high short circuit pulse current | Io+(HO) | | 250 | 300 | - | mA |
| Output low short circuit pulse current | Io-(HO) | | 500 | 600 | - | mA |
| Equivalent output resistance | ROP(HO) | | - | - | 60 | Ω |
| | RON(HO) | | - | - | 30 | Ω |
| High level output voltage, VB-VLO | VOH(LO) | Io=0 | - | - | 0.1 | V |
| Low level output voltage, VLO | VOL(LO) | Io=0 | - | - | 0.1 | V |
| Output high short circuit pulse current | Io+(LO) | | 250 | - | - | mA |
| Output low short circuit pulse current | Io-(LO) | | 500 | - | - | mA |
| Equivalent output resistance | ROP(LO) | | - | - | 60 | Ω |
| | RON(LO) | | - | - | 30 | Ω |

Dynamic Electrical Characteristics

Unless otherwise specified, -40°C <= Ta <= 125°C, V_{CC} = 15V, V_{BS} = 15V, V_S = 0V, C_L = 1nF.

| Parameter | Symbol | Conditions | Min. | Typ. | Max. | Unit |
|--|------------------|--|-------------|-------------|--------------|------|
| Turn-on propagation delay | t _{on} | V _S =0V | - | 750 | 1500 | ns |
| Turn-off propagation delay | t _{off} | V _S =0V | - | 130 | 250 | ns |
| Turn -on rising time | t _r | - | - | 40 | 150 | ns |
| Turn -off falling time | t _f | - | - | 25 | 400 | ns |
| Dead time, LS turn-off to HS turn-on and HS turn-on to LS turn-off | DT | V _{IN} =0 or 5V@ VDT=1.2V V _{IN} =0 or 5V@ VDT=3.3V | 250 1600 | 650 2100 | 1200 2600 | ns |
| Dead time matching time | MDT | DT1 -DT2@ VDT=1.2V DT1 -DT2@ VDT=3.3V | - | 35 - | 110 300 | ns |
| Delay Matching, HS and LS turn-on | MTON | VDT=1.2V | - | 25 | 110 | ns |
| Delay Matching, HS and LS turn-off | MTOFF | VDT=1.2V | | 15 | 60 | ns |
| Shutdown propagation delay | Tsd | | - | 180 | 330 | ns |
| Switching Frequency | Fs1 | V _{CC} =V _{BS} =20V | - | - | 200 | KHz |
| | Fs2 | V _{CC} =V _{BS} =5.5V | - | - | 200 | KHZ |

Typical Application Circuit



VDT = $V_{dd} \cdot R_2 / (R_1 + R_2)$. V_{dd} is output voltage of Microcontroller.

The operating range that allows a VDT range of 1.2~3.3V.

When pulled lower than V_{DT} [Typ. 0.5V] the device is shutdown.

Care must be taken to avoid below threshold spikes on pin 3 that can cause undesired shut down of the IC.

For this reason the connection of the components between pin 3 and ground has to be as short as possible.

And a capacitor (Typ. 0.02 uF) between pin 3 and COM can prevent this spike. This pin can not be left floating for the same reason.

Typical Waveforms

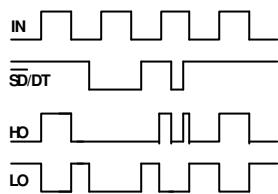


Figure 1. Input/output Timing Diagram

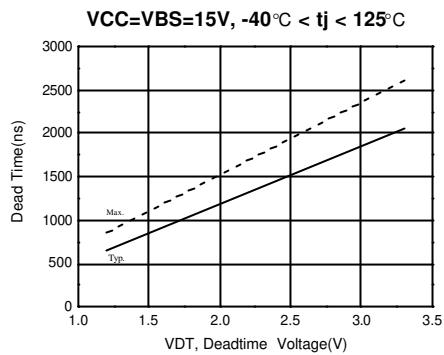


Figure 2. Dead Time VS VDT

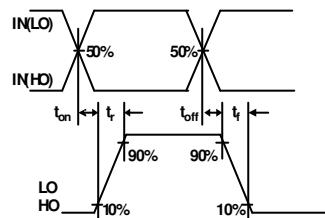


Figure 3. Switching Time Waveform Definitions

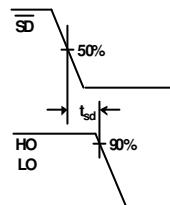


Figure 4. Shutdown Waveform Definitions

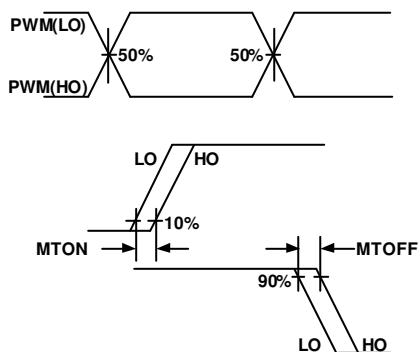


Figure 5. Delay Matching Waveform Definitions

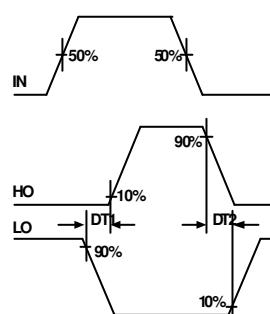


Figure 6. Dead Time Waveform Definitions

Performance Graphs (This performance graphs based on ambient temperature -40°C ~125°C)

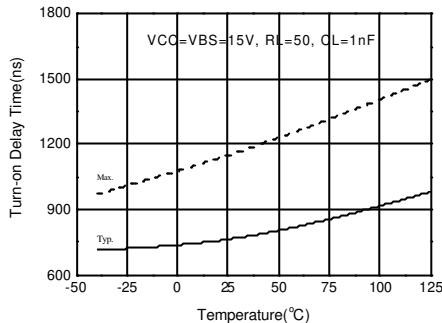


Figure 7a. Turn-On Delay Time of HO vs VBS Temperature

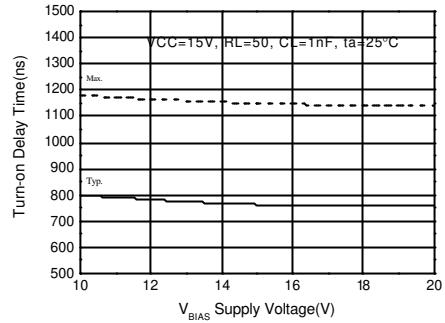


Figure 7b. Turn-On Delay Time of HO vs VBS Supply Voltage

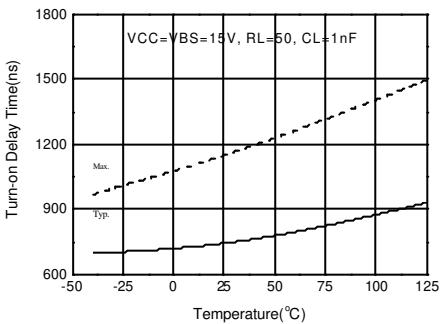


Figure 8a. Turn-On Delay Time of LO vs Temperature

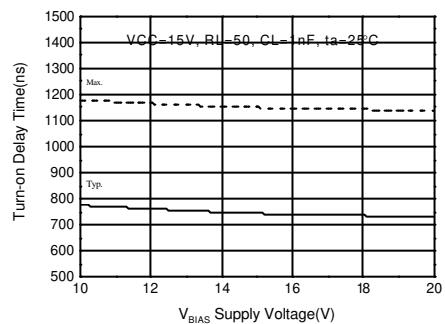


Figure 8b. Turn-On Delay Time of LO vs VBS Supply Voltage

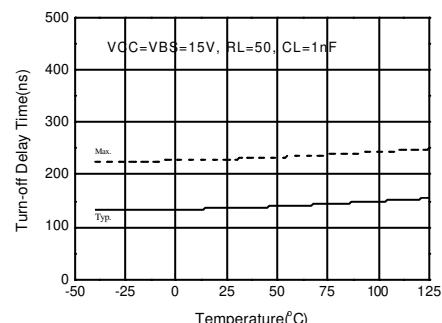


Figure 9a. Turn-Off Delay Time of HO vs Temperature

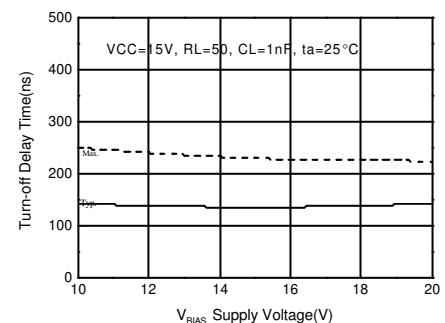


Figure 9b. Turn-Off Delay Time of HO vs VBS Supply Voltage

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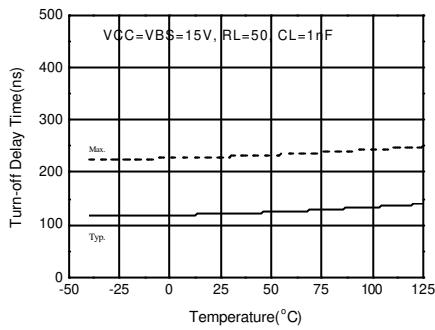


Figure 10a. Turn-Off Delay Time of LO vs Temperature

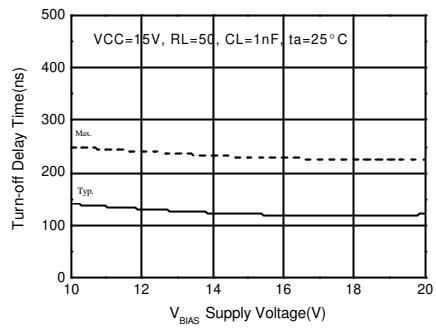


Figure 10b. Turn-Off Delay Time of LO vs VBS Supply Voltage

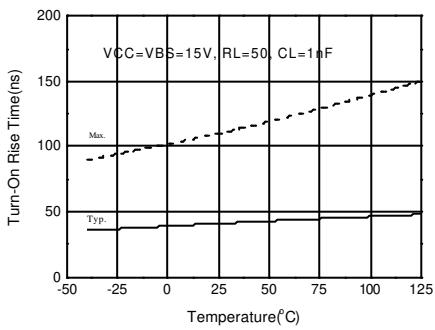


Figure 11a. Turn-On Rise Time of HO vs Temperature

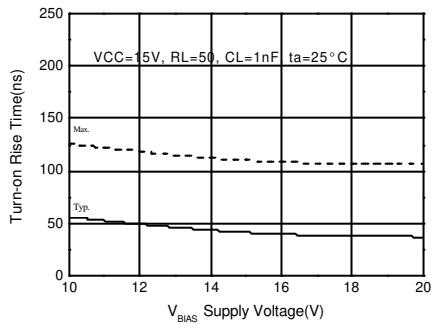


Figure 11b. Turn-On Rise Time vs of HO VBS Supply Voltage

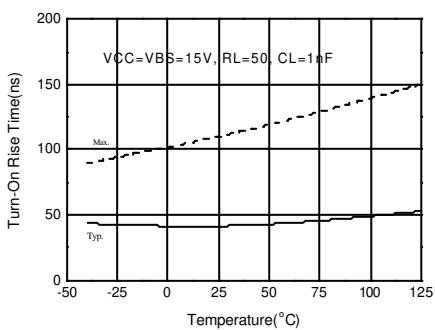


Figure 12a. Turn-On Rise Time of LO vs Temperature

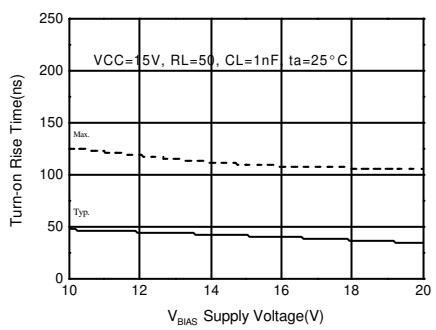


Figure 12b. Turn-On Rise Time of LO vs VBS Supply Voltage

FAN7080_F085 Half Bridge Gate Driver

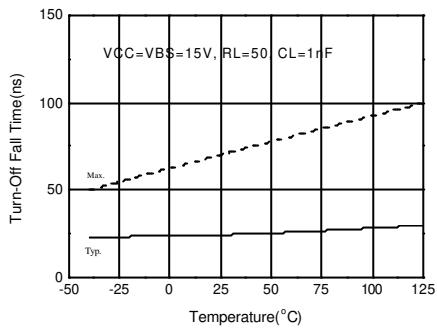


Figure 13a. Turn-Off Fall Time of HO vs Temperature

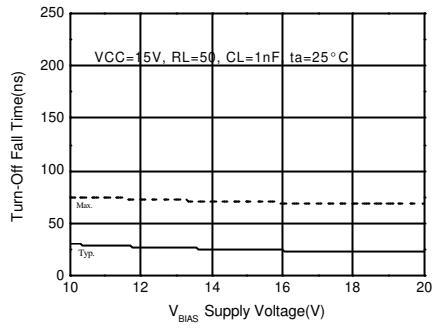


Figure 13b. Turn-Off Fall Time of HO vs VBS Supply Voltage

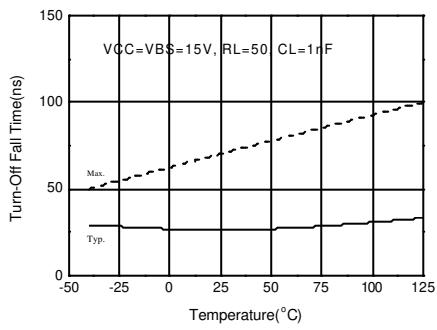


Figure 14a. Turn-Off Fall Time of LO vs Temperature

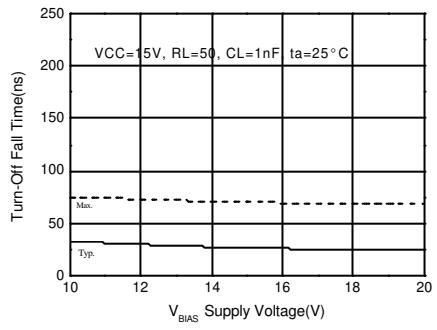


Figure 14b. Turn-Off Fall Time of LO vs BS Supply Voltage

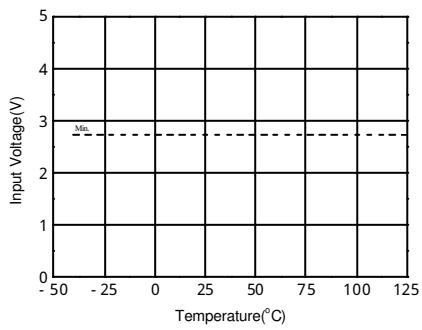


Figure 15a. Logic 0 Input Voltage vs Temperature

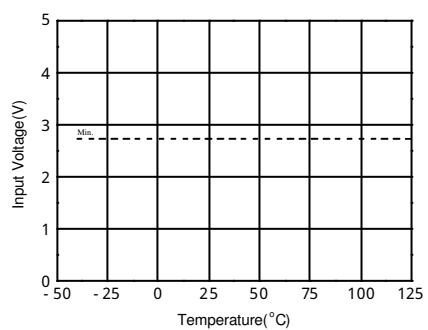
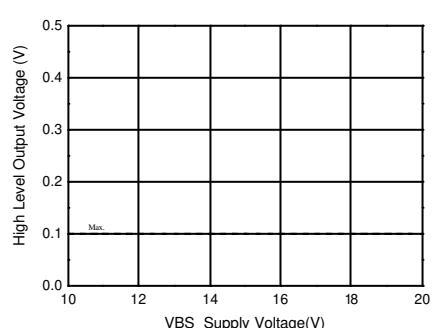
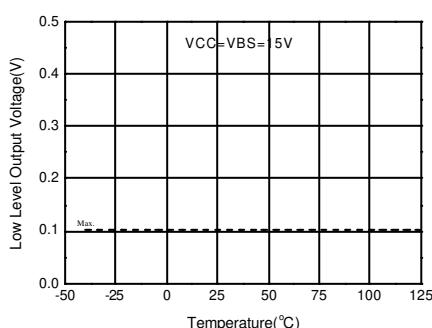
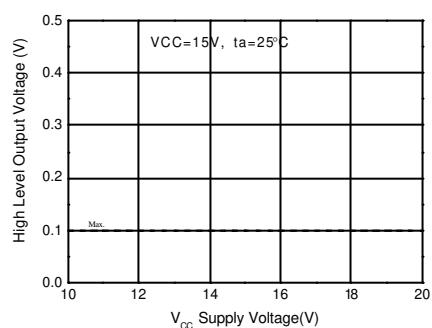
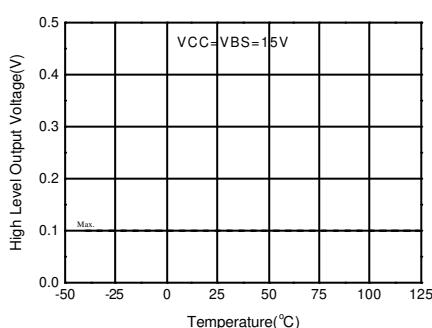
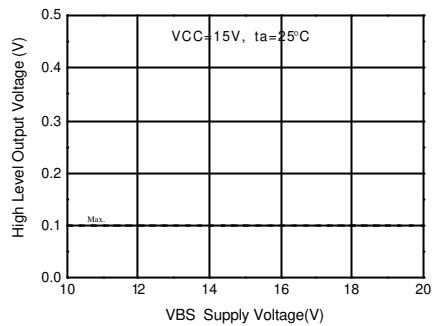
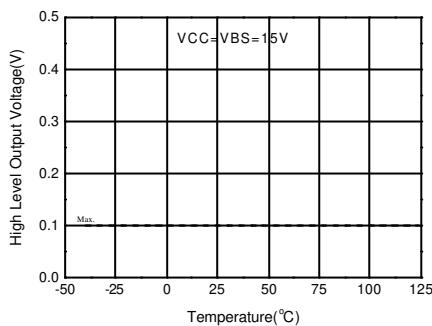
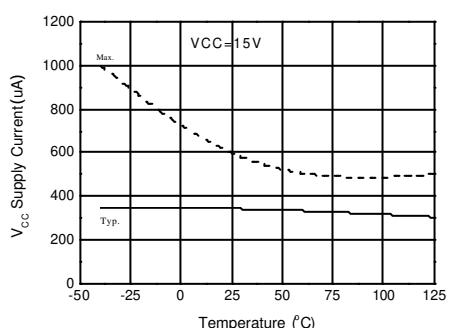
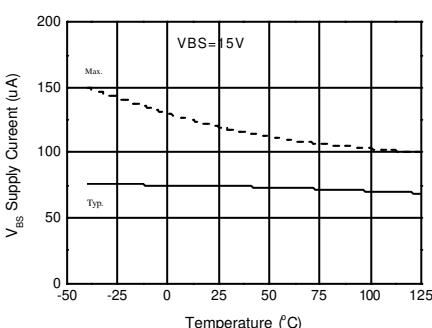
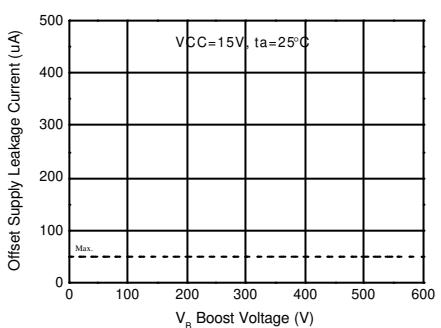
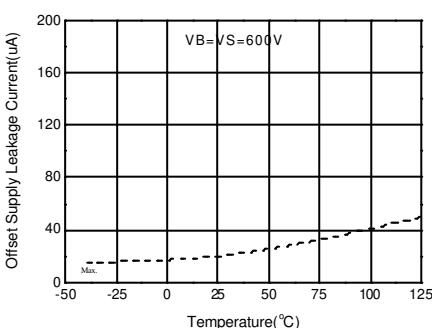
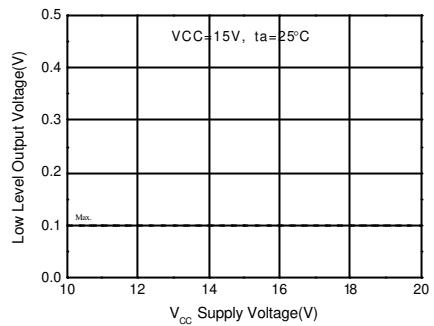
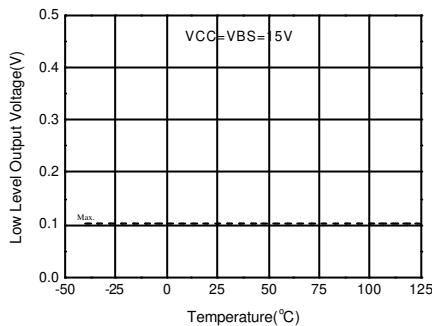


Figure 15b. Logic 1 Input Voltage vs Temperature

FAN7080_F085 Half Bridge Gate Driver



FAN7080_F085 Half Bridge Gate Driver



FAN7080_F085 Half Bridge Gate Driver

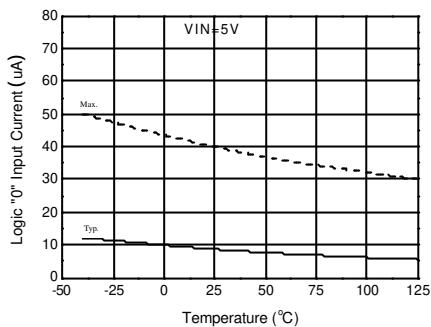


Figure 23a. Logic 1 Input Current vs Temperature

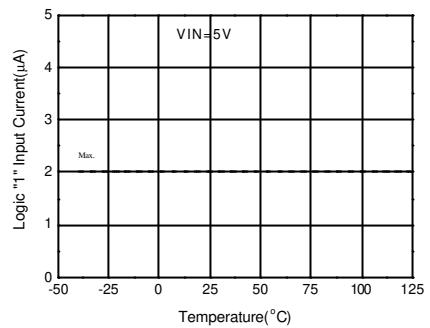


Figure 23b. Logic 0 Input Current vs Temperature

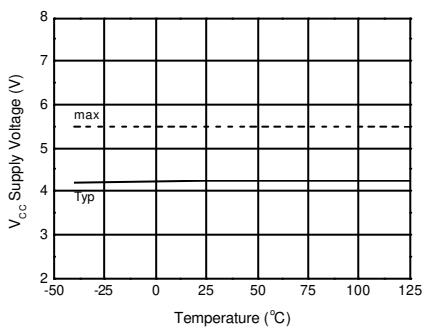


Figure 24a. VCC UnderVoltage Threshold (+) vs Temperature

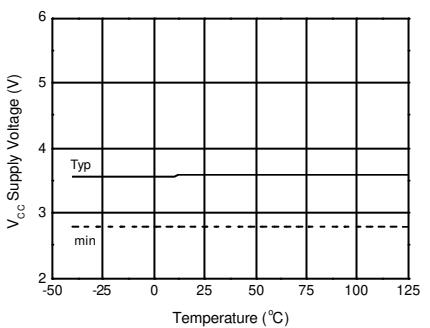


Figure 24b. VCC UnderVoltage Threshold(-) vs Temperature

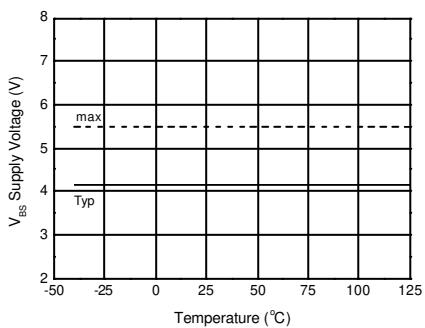


Figure 25a. VBS UnderVoltage Threshold (+) vs Temperature

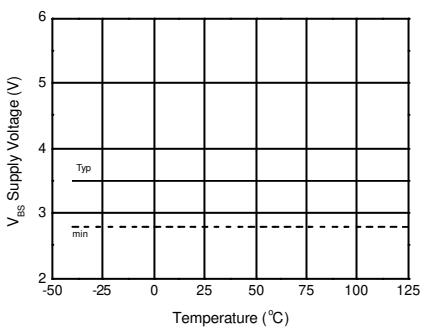


Figure 25b. VBS UnderVoltage Threshold(-) vs Temperature

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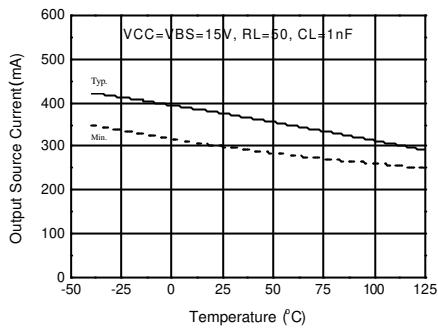


Figure 26a. Output Source Current of HO vs Temperature

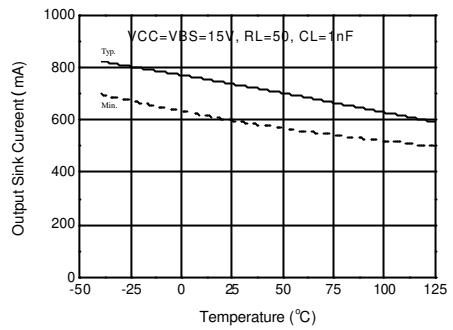


Figure 26b. Output Sink Current of HO vs Temperature

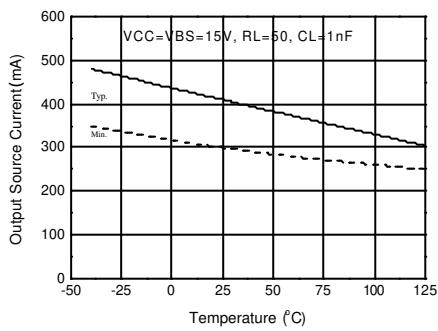


Figure 27a. Output Source Current of LO vs Temperature

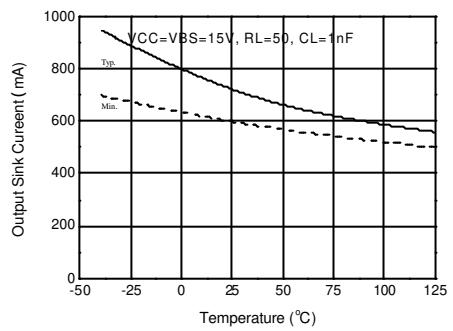


Figure 27b. Output Sink Current of LO vs Temperature

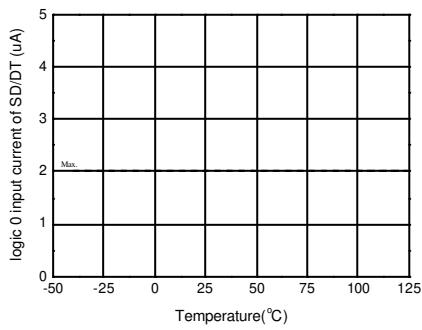


Figure 28. Logic 0 Input Current of SD/DT vs Temperature

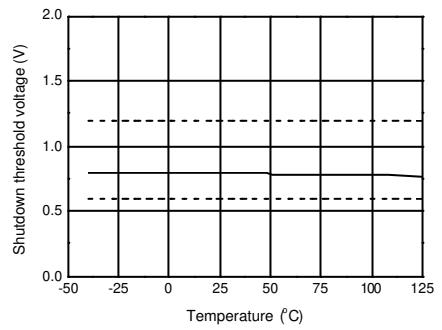


Figure 29. Shutdown Threshold of vs Temperature

FAN7080_F085 Half Bridge Gate Driver

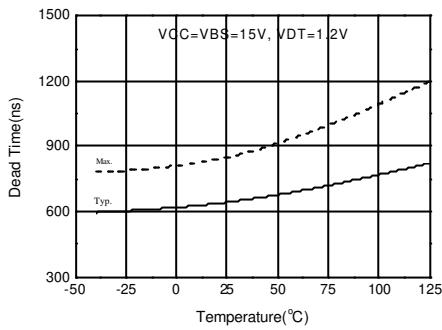


Figure 30. Deadtime vs Temperature

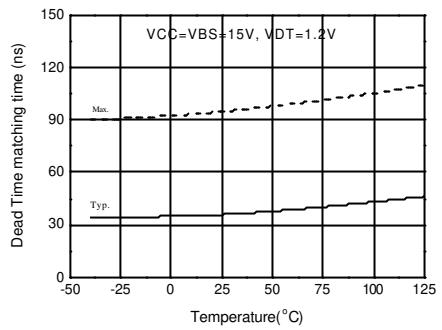


Figure 31. Deadtime Matching Time vs Temperature

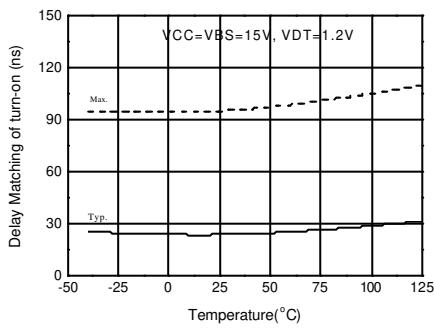


Figure 32. Turn-On Delay Matching vs Temperature

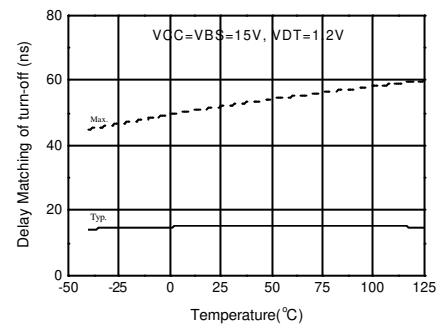


Figure 33. Turn_Off Delay Matching vs Temperature

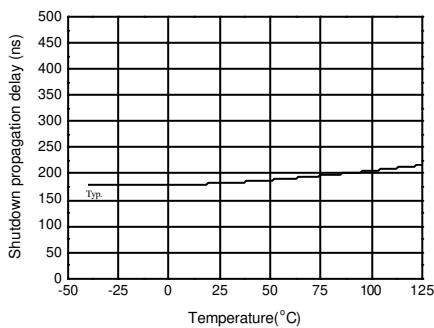


Figure 34. Shutdown Propagation Delay vs Temperature

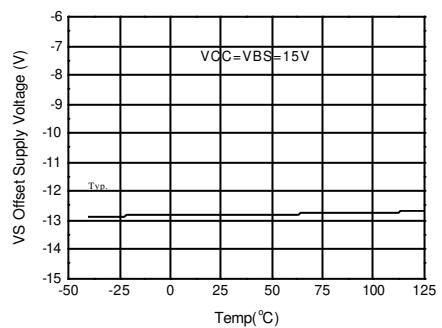


Figure 35. Maximum VS Negative Offset of vs Temperature

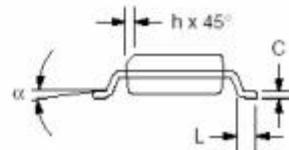
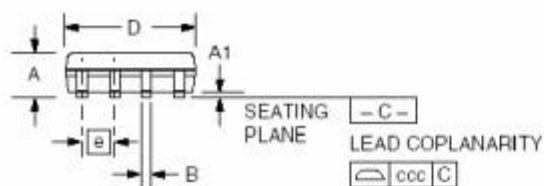
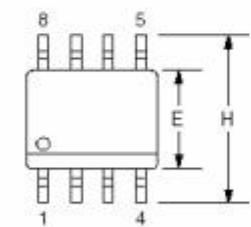
Package Dimensions

8-SOP

| Symbol | Inches | | Millimeters | | Notes |
|----------|----------|------|-------------|------|-------|
| | Min. | Max. | Min. | Max. | |
| A | .053 | .069 | 1.35 | 1.75 | |
| A1 | .004 | .010 | 0.10 | 0.25 | |
| B | .013 | .020 | 0.33 | 0.51 | |
| C | .0075 | .010 | 0.20 | 0.25 | 5 |
| D | .189 | .197 | 4.80 | 5.00 | 2 |
| E | .150 | .158 | 3.81 | 4.01 | 2 |
| g | .050 BSC | | 1.27 BSC | | |
| H | .228 | .244 | 5.79 | 6.20 | |
| h | .010 | .020 | 0.25 | 0.50 | |
| L | .016 | .050 | 0.40 | 1.27 | 3 |
| N | 8 | | 8 | | 6 |
| α | 0° | 8° | 0° | 8° | |
| ccc | — | .004 | — | 0.10 | |

Notes:

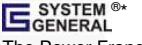
- Dimensioning and tolerancing per ANSI Y14.5M-1982.
- "D" and "E" do not include mold flash. Mold flash or protrusions shall not exceed .010 inch (0.25mm).
- "L" is the length of terminal for soldering to a substrate.
- Terminal numbers are shown for reference only.
- "C" dimension does not include solder finish thickness.
- Symbol "N" is the maximum number of terminals.





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| FastvCore™ | PDP SPM™ |  | XSTM |
| FlashWriter®* | Power-SPM™ | The Power Franchise® | |
| FPS™ | PowerTrench® | | |
| F-PFS™ | PowerXSTM | | |

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|--------------------------|-----------------------|---|
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